



MT47H512M4EB-187E:C

Part Number:	MT47H512M4EB-187E:C
Manufacturer/Brand:	Micron Technology
Product description	IC DRAM 2G PARALLEL 60FBGA
Datasheets:	 MT47H512M4EB-187E:C.pdf
RoHs Status	 Lead free / RoHS Compliant
Stock Condition	2604 pcs stock
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

Image may be representation. See specifications for product details.

Specifications of MT47H512M4EB-187E:C

PART NUMBER	MT47H512M4EB-187E:C
MANUFACTURER	Micron Technology
DESCRIPTION	IC DRAM 2G PARALLEL 60FBGA
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
QUANTITY AVAILABLE	2604 pcs
DATA SHEET	 MT47H512M4EB-187E:C.pdf
WRITE CYCLE TIME - WORD, PAGE	15ns
VOLTAGE - SUPPLY	1.7 V ~ 1.9 V
TECHNOLOGY	SDRAM - DDR2
SUPPLIER DEVICE PACKAGE	60-FBGA (9x11.5)
SERIES	-
PACKAGING	Tray
PACKAGE / CASE	60-TFBGA
OPERATING TEMPERATURE	0°C ~ 85°C (TC)
MOUNTING TYPE	Surface Mount
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Volatile
MEMORY SIZE	2Gb (512M x 4)
MEMORY INTERFACE	Parallel
MEMORY FORMAT	DRAM
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	SDRAM - DDR2 Memory IC 2Gb (512M x 4) Parallel 533MHz 350ps 60-FBGA (9x11.5)
CLOCK FREQUENCY	533MHz
BASE PART NUMBER	MT47H512M4
ACCESS TIME	350ps

Related Tags

Micron Technology MT47H512M4EB-187E:C	MT47H512M4EB-187E:C Distributor	MT47H512M4EB-187E:C Supplier
MT47H512M4EB-187E:C Price	MT47H512M4EB-187E:C Pictures	MT47H512M4EB-187E:C Image
MT47H512M4EB-187E:C PDF Datasheet	MT47H512M4EB-187E:C Download Datasheet	MT47H512M4EB-187E:C Datasheet
MT47H512M4EB-187E:C Stock	Buy MT47H512M4EB-187E:C	Buy Micron Technology MT47H512M4EB-187E:C
Micron Technology MT47H512M4EB-187E:C	Micron Technology Supplier	Micron Technology Distributor
Micron Technology MT47H512M4EB-187E:C	Micron Technology Inc. MT47H512M4EB-187E:C	

Related Products

 MT47H512M4EB-3:C Manufacturers: Micron Technology Description: IC DRAM 2G PARALLEL 60FBGA In stock: 2942 pcs RFQ	 MT47H512M4EB-25E:C TR Manufacturers: Micron Technology Description: IC DRAM 2G PARALLEL 60FBGA In stock: 4819 pcs RFQ
 MT47H512M4THN-25E:H Manufacturers: Micron Technology Description: IC DRAM 2G PARALLEL 63FBGA In stock: 4134 pcs RFQ	 MT47H32M8BP-5E:B Manufacturers: Micron Technology Description: IC DRAM 256M PARALLEL 60FBGA In stock: 8508 pcs RFQ
 MT47H32M8BP-37V:B Manufacturers: Micron Technology Description: IC DRAM 256M PARALLEL 60FBGA In stock: 9648 pcs RFQ	 MT47H512M4THN-25E:M Manufacturers: Micron Technology Description: IC DRAM 2G PARALLEL 400MHZ In stock: 3876 pcs RFQ
 MT47H512M4EB-25E:C Manufacturers: Micron Technology Description: IC DRAM 2G PARALLEL 60FBGA In stock: 3935 pcs RFQ	 MT47H512M4THN-25E:M TR Manufacturers: Micron Technology Description: IC DRAM 2G PARALLEL 63FBGA In stock: 4157 pcs RFQ
 MT47H32M8BP-3:B TR Manufacturers: Micron Technology Description: IC DRAM 256M PARALLEL 60FBGA In stock: 9938 pcs RFQ	 MT47H32M8BP-37E:B TR Manufacturers: Micron Technology Description: IC DRAM 256M PARALLEL 60FBGA In stock: 6681 pcs RFQ
 MT47H32M16U67A3WC1 Manufacturers: Micron Technology Description: IC DRAM 512M PARALLEL WAFER In stock: 11111 pcs RFQ	 MT47H32M8BP-5E:B TR Manufacturers: Micron Technology Description: IC DRAM 256M PARALLEL 60FBGA In stock: 11658 pcs RFQ